



## ST730C..L SERIES

PHASE CONTROL THYRISTORS

Hockey Puk Version

### Features

- Center amplifying gate
- Metal case with ceramic insulator
- International standard case TO-200AC (B-PUK)

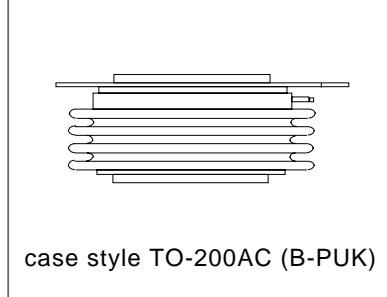
990A

### Typical Applications

- DC motor controls
- Controlled DC power supplies
- AC controllers

### Major Ratings and Characteristics

| Parameters        | ST730C..L        | Units          |                   |
|-------------------|------------------|----------------|-------------------|
| $I_{T(AV)}$       | 990              | A              |                   |
| @ $T_{hs}$        | 55               | °C             |                   |
| $I_{T(RMS)}$      | 2000             | A              |                   |
| @ $T_{hs}$        | 25               | °C             |                   |
| $I_{TSM}$         | @ 50Hz<br>@ 60Hz | 17800<br>18700 | A                 |
| $I^2t$            | @ 50Hz<br>@ 60Hz | 1591<br>1452   | KA <sup>2</sup> s |
| $V_{DRM}/V_{RRM}$ | 800 to 2000      | V              |                   |
| $t_q$             | typical          | 150            | μs                |
| $T_J$             |                  | - 40 to 125    | °C                |



case style TO-200AC (B-PUK)

## ST730C..L Series

Bulletin I25191 rev. D 04/03

International  
**IR** Rectifier

### ELECTRICAL SPECIFICATIONS

#### Voltage Ratings

| Type number | Voltage Code | $V_{DRM}/V_{RRM}$ , max. repetitive peak and off-state voltage V | $V_{RSM}$ , maximum non-repetitive peak voltage V | $I_{DRM}/I_{RRM}$ max. @ $T_J = T_J$ max mA |
|-------------|--------------|--|---|---|
| ST730C..L   | 08           | 800  | 900   | 80  |
|             | 12           | 1200   | 1300  |   |
|             | 14           | 1400   | 1500  |   |
|             | 16           | 1600   | 1700  |   |
|             | 18           | 1800   | 1900  |   |
|             | 20           | 2000   | 2100  |   |

#### On-state Conduction

| Parameter  | ST730C..L | Units              | Conditions   |
|--|-----------|--------------------|--|
| $I_{T(AV)}$ Max. average on-state current @ Heatsink temperature | 990 (375) | A                  | 180° conduction, half sine wave  |
|  | 55 (85)   | °C                 | double side (single side) cooled   |
| $I_{T(RMS)}$ Max. RMS on-state current                           | 2000      | A                  | DC @ 25°C heatsink temperature double side cooled                                    |
| $I_{TSM}$ Max. peak, one-cycle non-repetitive surge current      | 17800     |                    | $t = 10\text{ms}$  |
|  | 18700     |                    | $t = 8.3\text{ms}$   |
|  | 15000     |                    | $t = 10\text{ms}$  |
|  | 15700     |                    | $t = 8.3\text{ms}$   |
| $I^2t$ Maximum $I^2t$ for fusing                                 | 1591      | KA <sup>2</sup> s  | $t = 10\text{ms}$  |
|  | 1452      |                    | $t = 8.3\text{ms}$   |
|  | 1125      |                    | $t = 10\text{ms}$  |
|  | 1027      |                    | $t = 8.3\text{ms}$   |
| $I^2\sqrt{t}$ Maximum $I^2\sqrt{t}$ for fusing                   | 15910     | KA <sup>2</sup> √s | $t = 0.1$ to $10\text{ms}$ , no voltage reapplied                                    |
| $V_{T(TO)1}$ Low level value of threshold voltage                | 0.98      | V                  | $(16.7\% \times \pi \times I_{T(AV)} < I < \pi \times I_{T(AV)})$ , $T_J = T_J$ max. |
| $V_{T(TO)2}$ High level value of threshold voltage               | 1.12      |                    | $(I > \pi \times I_{T(AV)})$ , $T_J = T_J$ max.                                      |
| $r_{t1}$ Low level value of on-state slope resistance            | 0.32      | mΩ                 | $(16.7\% \times \pi \times I_{T(AV)} < I < \pi \times I_{T(AV)})$ , $T_J = T_J$ max. |
| $r_{t2}$ High level value of on-state slope resistance           | 0.27      |                    | $(I > \pi \times I_{T(AV)})$ , $T_J = T_J$ max.                                      |
| $V_{TM}$ Max. on-state voltage                                   | 1.62      | V                  | $I_{pk} = 2000\text{A}$ , $T_J = T_J$ max, $t_p = 10\text{ms}$ sine pulse            |
| $I_H$ Maximum holding current                                    | 600       | mA                 |  |
| $I_L$ Typical latching current                                   | 1000      |                    | $T_J = 25^\circ\text{C}$ , anode supply 12V resistive load                           |

#### Switching

| Parameter   | ST730C..L | Units | Conditions   |
|---|-----------|-------|--|
| $di/dt$ Max. non-repetitive rate of rise of turned-on current | 1000      | A/μs  | Gate drive 20V, $20\Omega$ , $t_r \leq 1\mu\text{s}$<br>$T_J = T_J$ max, anode voltage $\leq 80\%$ $V_{DRM}$   |
| $t_d$ Typical delay time                                      | 1.0       | μs    | Gate current 1A, $di_g/dt = 1\text{A}/\mu\text{s}$<br>$V_d = 0.67\% V_{DRM}$ , $T_J = 25^\circ\text{C}$  |
| $t_q$ Typical turn-off time                                   | 150       |       | $I_{TM} = 750\text{A}$ , $T_J = T_J$ max, $di/dt = 60\text{A}/\mu\text{s}$ , $V_R = 50\text{V}$<br>$dv/dt = 20\text{V}/\mu\text{s}$ , Gate 0V $100\Omega$ , $t_p = 500\mu\text{s}$ |

### Blocking

| Parameter   | ST730C..L | Units      | Conditions                                       |
|---|-----------|------------|--|
| dv/dt Maximum critical rate of rise of off-state voltage  | 500       | V/ $\mu$ s | $T_J = T_J$ max. linear to 80% rated $V_{DRM}$   |
| $I_{DRM}$ Max. peak reverse and off-state leakage current | 80        | mA         | $T_J = T_J$ max, rated $V_{DRM}/V_{RRM}$ applied |

### Triggering

| Parameter                                    | ST730C..L                | Units                 | Conditions   |
|--|--------------------------|-----------------------|--|
| $P_{GM}$ Maximum peak gate power             | 10.0                     | W                     | $T_J = T_J$ max, $t_p \leq 5ms$  |
| $P_{G(AV)}$ Maximum average gate power       | 2.0                      |                       | $T_J = T_J$ max, $f = 50Hz, d\% = 50$  |
| $I_{GM}$ Max. peak positive gate current     | 3.0                      | A                     | $T_J = T_J$ max, $t_p \leq 5ms$  |
| $+V_{GM}$ Maximum peak positive gate voltage | 20                       | V                     | $T_J = T_J$ max, $t_p \leq 5ms$  |
| $-V_{GM}$ Maximum peak negative gate voltage | 5.0                      |                       |  |
| $I_{GT}$ DC gate current required to trigger | TYP.<br>200<br>100<br>50 | MAX.<br>-<br>200<br>- | mA $T_J = -40^{\circ}C$<br>$T_J = 25^{\circ}C$<br>$T_J = 125^{\circ}C$<br>Max. required gate trigger/ current/voltage are the lowest value which will trigger all units 12V anode-to-cathode applied |
| $V_{GT}$ DC gate voltage required to trigger | 2.5<br>1.8<br>1.1        | -<br>3.0<br>-         | V $T_J = -40^{\circ}C$<br>$T_J = 25^{\circ}C$<br>$T_J = 125^{\circ}C$  |
| $I_{GD}$ DC gate current not to trigger      | 10                       | mA                    | $T_J = T_J$ max Max. gate current/voltage not to trigger is the max. value which will not trigger any unit with rated $V_{DRM}$ anode-to-cathode applied   |
| $V_{GD}$ DC gate voltage not to trigger      | 0.25                     | V                     |  |

### Thermal and Mechanical Specification

| Parameter  | ST730C..L        | Units        | Conditions   |
|--|------------------|--------------|--|
| $T_J$ Max. operating temperature range                     | -40 to 125       | $^{\circ}$ C |  |
| $T_{stg}$ Max. storage temperature range                   | -40 to 150       |              |  |
| $R_{thJ-hs}$ Max. thermal resistance, junction to heatsink | 0.073<br>0.031   | K/W          | DC operation single side cooled<br>DC operation double side cooled |
| $R_{thC-hs}$ Max. thermal resistance, case to heatsink     | 0.011<br>0.006   | K/W          | DC operation single side cooled<br>DC operation double side cooled |
| F Mounting force, $\pm 10\%$                               | 14700<br>(1500)  | N<br>(Kg)    |  |
| wt Approximate weight                                      | 255              | g            |  |
| Case style   | TO-200AC (B-PUK) |              | See Outline Table  |

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Bulletin I25191 rev. D 04/03

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### $\Delta R_{thJ-hs}$ Conduction

(The following table shows the increment of thermal resistance  $R_{thJ-hs}$  when devices operate at different conduction angles than DC)

| Conduction angle | Sinusoidal conduction |             | Rectangular conduction |             | Units | Conditions                 |
|------------------|-----------------------|-------------|------------------------|-------------|-------|----------------------------|
|                  | Single Side           | Double Side | Single Side            | Double Side |       |                            |
| 180°             | 0.009                 | 0.009       | 0.006                  | 0.006       | K/W   | $T_J = T_{J \text{ max.}}$ |
| 120°             | 0.011                 | 0.011       | 0.010                  | 0.011       |       |                            |
| 90°              | 0.014                 | 0.014       | 0.015                  | 0.015       |       |                            |
| 60°              | 0.020                 | 0.020       | 0.021                  | 0.021       |       |                            |
| 30°              | 0.036                 | 0.036       | 0.036                  | 0.036       |       |                            |

### Ordering Information Table

| Device Code |   | ST 73 0 C 20 L 1  |   |   |   |   |   |   |   |
|-------------|---|---|---|---|---|---|---|---|---|
|             |   | 1   | 2 | 3 | 4 | 5 | 6 | 7 | 8 |
| 1           | - | Thyristor   |   |   |   |   |   |   |   |
| 2           | - | Essential part number   |   |   |   |   |   |   |   |
| 3           | - | 0 = Converter grade   |   |   |   |   |   |   |   |
| 4           | - | C = Ceramic Puk   |   |   |   |   |   |   |   |
| 5           | - | Voltage code: Code x 100 = $V_{RRM}$ (See Voltage Rating Table)     |   |   |   |   |   |   |   |
| 6           | - | L = Puk Case TO-200AC (B-PUK)                                       |   |   |   |   |   |   |   |
| 7           | - | 0 = Eyelet terminals (Gate and Auxiliary Cathode Unsoldered Leads)  |   |   |   |   |   |   |   |
|             |   | 1 = Fast-on terminals (Gate and Auxiliary Cathode Unsoldered Leads) |   |   |   |   |   |   |   |
|             |   | 2 = Eyelet terminals (Gate and Auxiliary Cathode Soldered Leads)    |   |   |   |   |   |   |   |
|             |   | 3 = Fast-on terminals (Gate and Auxiliary Cathode Soldered Leads)   |   |   |   |   |   |   |   |
| 8           | - | Critical dv/dt: None = 500V/ $\mu$ sec (Standard selection)         |   |   |   |   |   |   |   |
|             |   | L = 1000V/ $\mu$ sec (Special selection)                            |   |   |   |   |   |   |   |

Outline Table

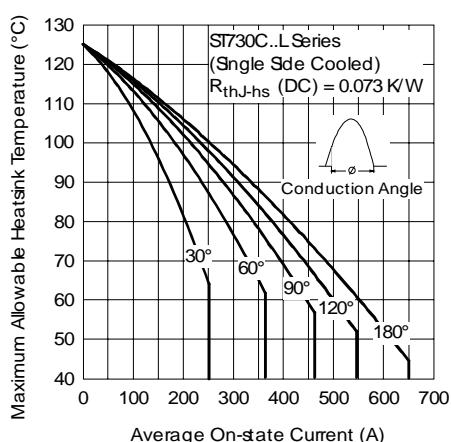
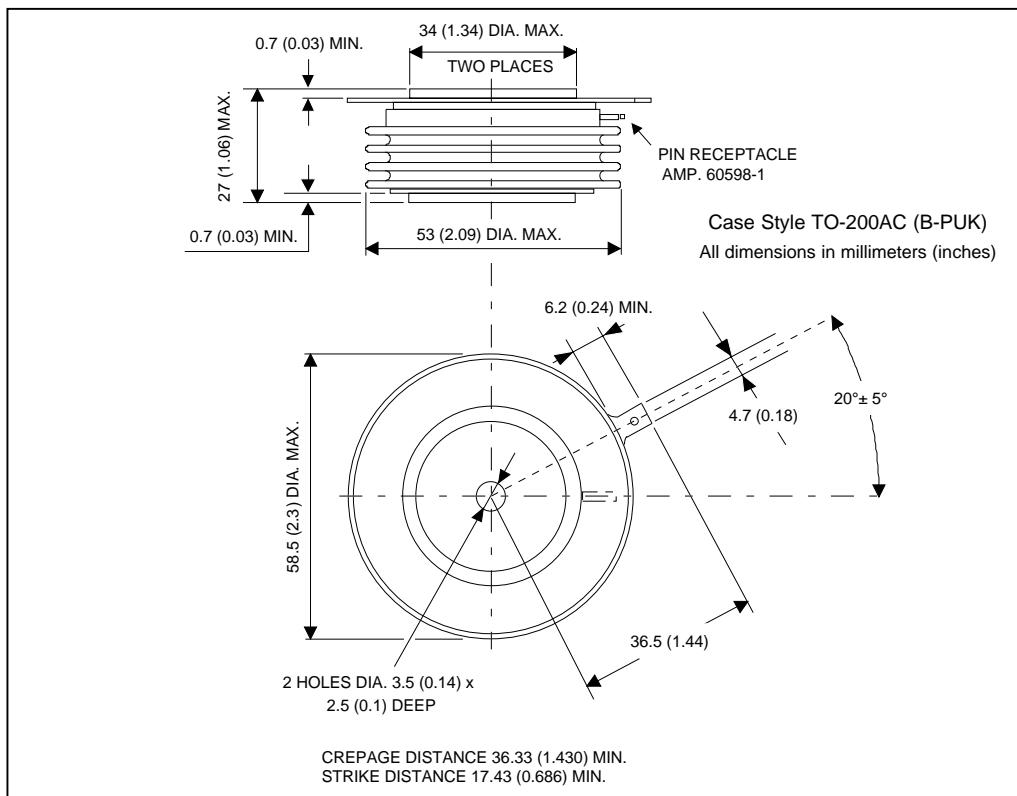


Fig. 1 - Current Ratings Characteristics

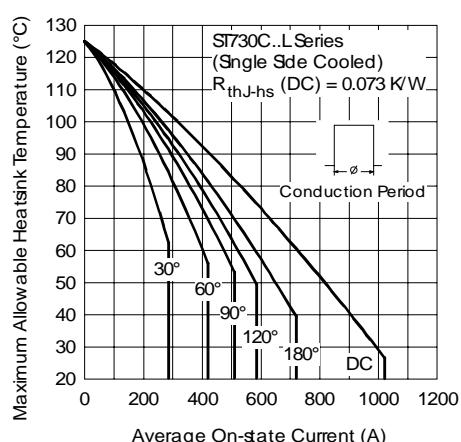


Fig. 2 - Current Ratings Characteristics

## ST730C..L Series

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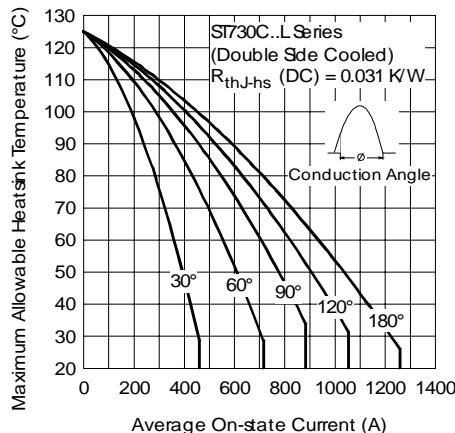


Fig. 3 - Current Ratings Characteristics

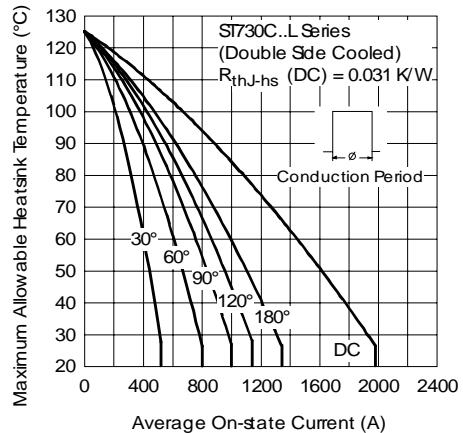


Fig. 4 - Current Ratings Characteristics

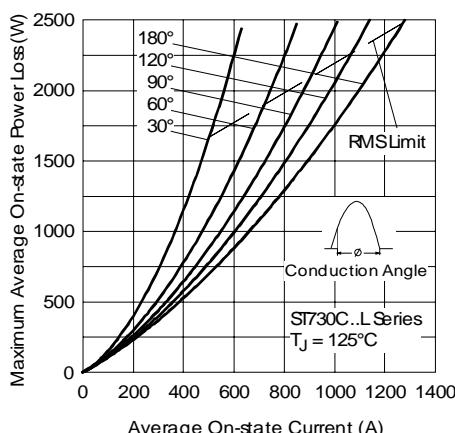


Fig. 5 - On-state Power Loss Characteristics

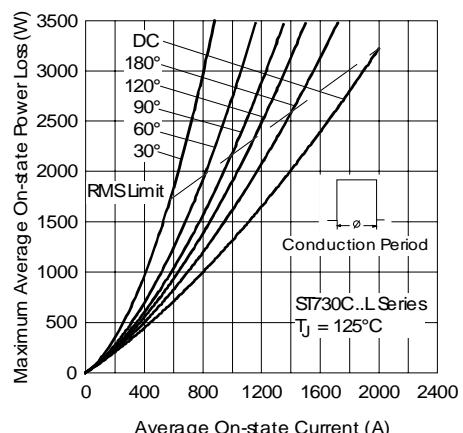


Fig. 6 - On-state Power Loss Characteristics

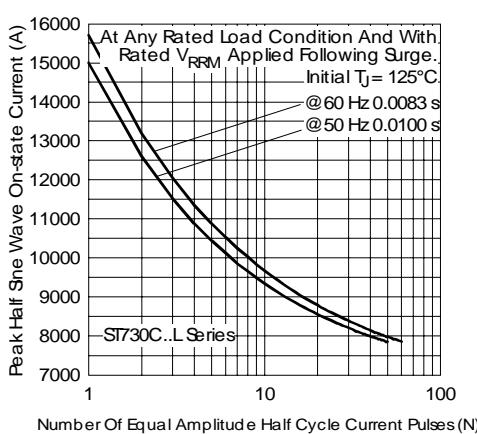


Fig. 7 - Maximum Non-Repetitive Surge Current  
Single and Double Side Cooled

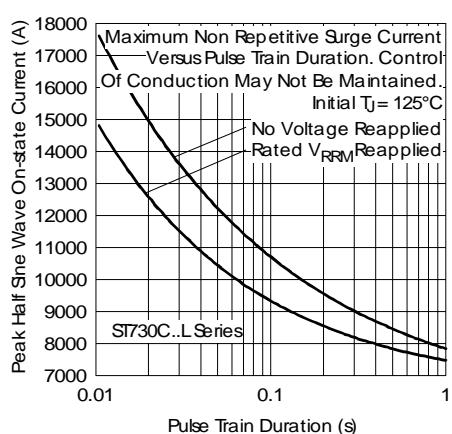


Fig. 8 - Maximum Non-Repetitive Surge Current  
Single and Double Side Cooled

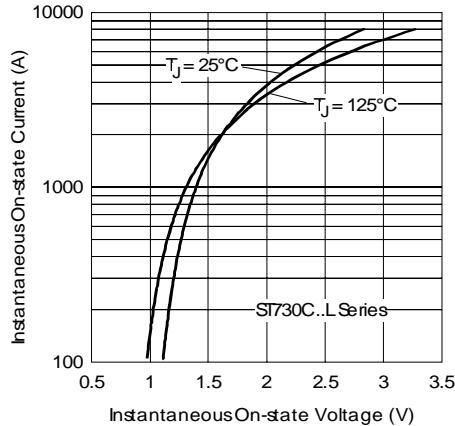


Fig. 9 - On-state Voltage Drop Characteristics

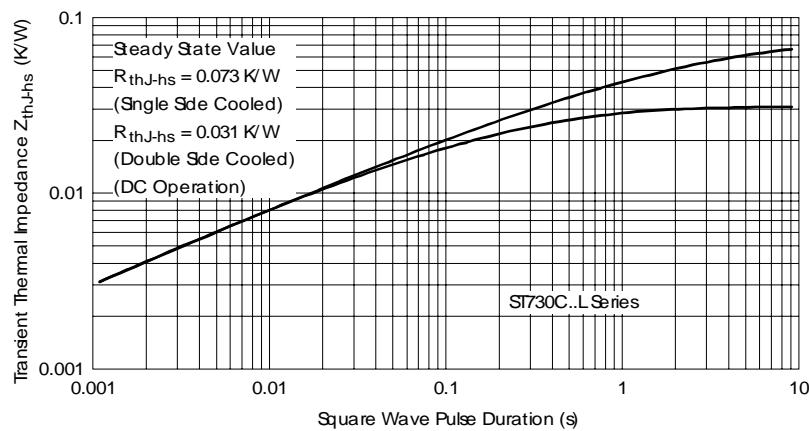


Fig. 10 - Thermal Impedance  $Z_{\text{thJ-hs}}$  Characteristics

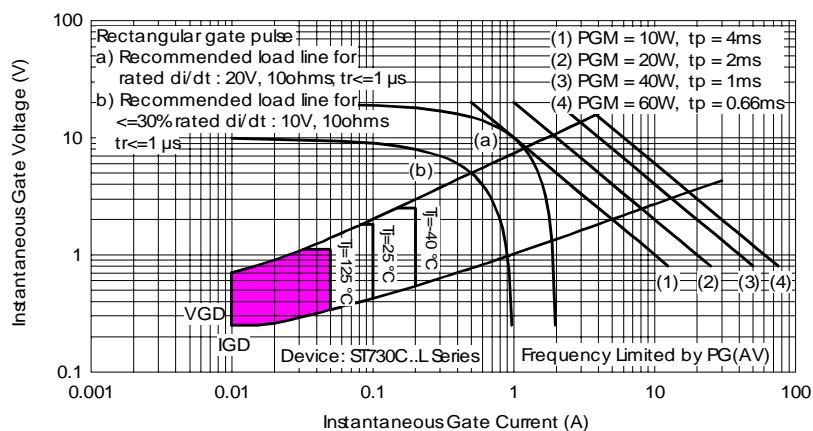


Fig. 11 - Gate Characteristics

## **ST730C..L Series**

Bulletin I25191 rev. D 04/03

International  
**IR** Rectifier

Data and specifications subject to change without notice.  
This product has been designed and qualified for Industrial Level.  
Qualification Standards can be found on IR's Web site.

International  
**IR** Rectifier

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